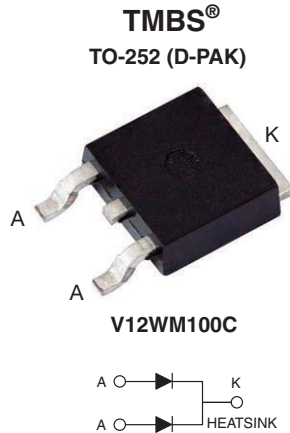


## Dual Trench MOS Barrier Schottky Rectifier

 Ultra Low  $V_F = 0.48\text{ V}$  at  $I_F = 3\text{ A}$ 


### FEATURES

- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-252 (D-PAK)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 6 A
$V_{RRM}$	100 V
$I_{FSM}$	90 A
$V_F$ at $I_F = 6\text{ A}$ ( $T_A = 125\text{ °C}$ )	0.57 V
$T_J$ max.	150 °C
Package	TO-252 (D-PAK)
Diode variation	Dual common cathode

MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V12WM100C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	12
		per diode	6
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	90	A
Operating junction and storage temperature range	$T_J, T_{STG}$	-40 to +150	°C

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 3\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.56	-	V
	$I_F = 6\text{ A}$			0.65	0.75	
	$I_F = 3\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.48	-	
	$I_F = 6\text{ A}$			0.57	0.66	
Reverse current per diode	$V_R = 100\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	-	300	$\mu\text{A}$
		$T_A = 125\text{ }^\circ\text{C}$		3	15	mA

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
 (2) Pulse test: Pulse width  $\leq 5\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V12WM100C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	2.4	$^\circ\text{C/W}$
	per device		1.2	
	per device	$R_{\theta JA}^{(1)(2)}$	65	

**Notes**

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$   
 (2) Free air, without heatsink

<b>ORDERING INFORMATION</b> (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V12WM100C-M3/I	0.38	I	2500/reel	13" diameter plastic tape and reel

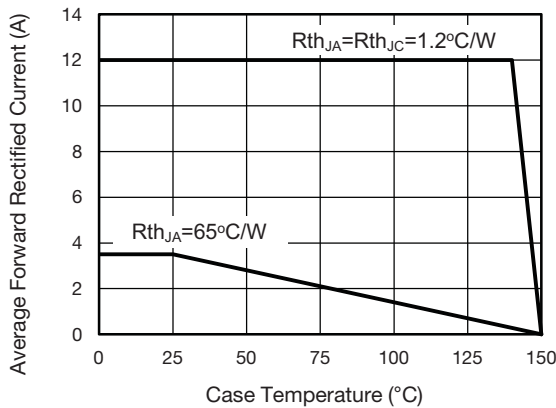
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

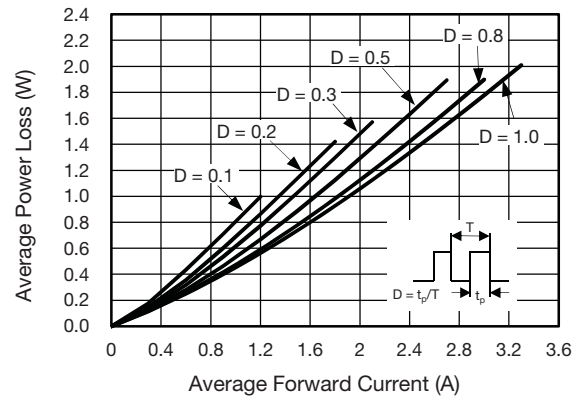


Fig. 2 - Forward Power Loss Characteristics Per Diode

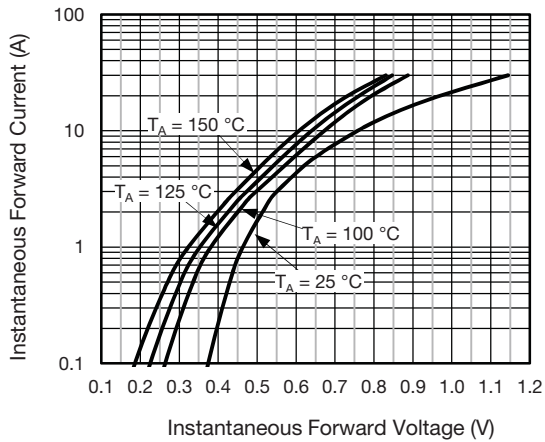


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

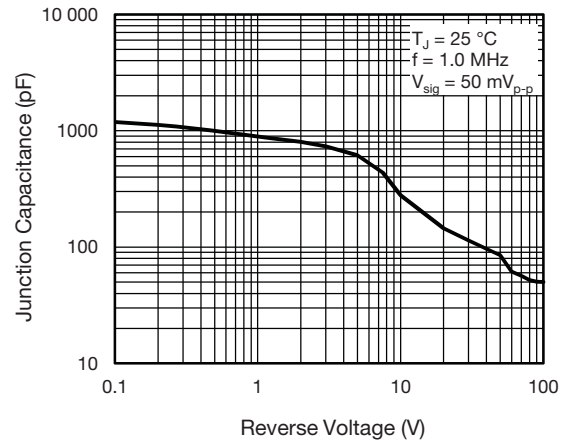


Fig. 5 - Typical Junction Capacitance Per Diode

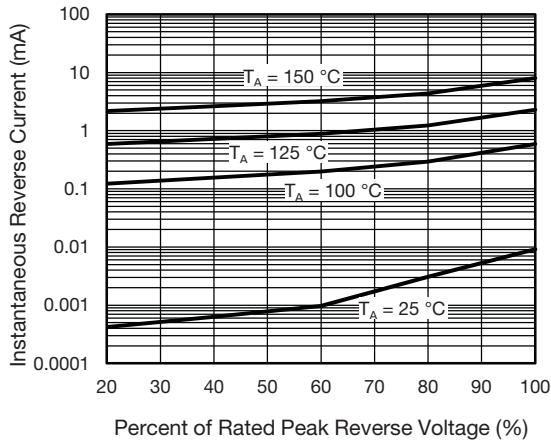


Fig. 4 - Typical Reverse Characteristics Per Diode

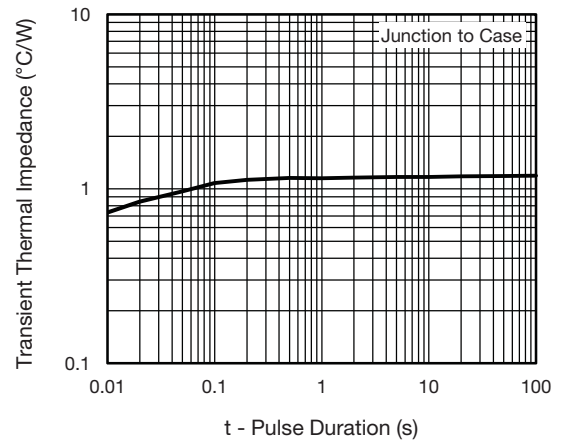
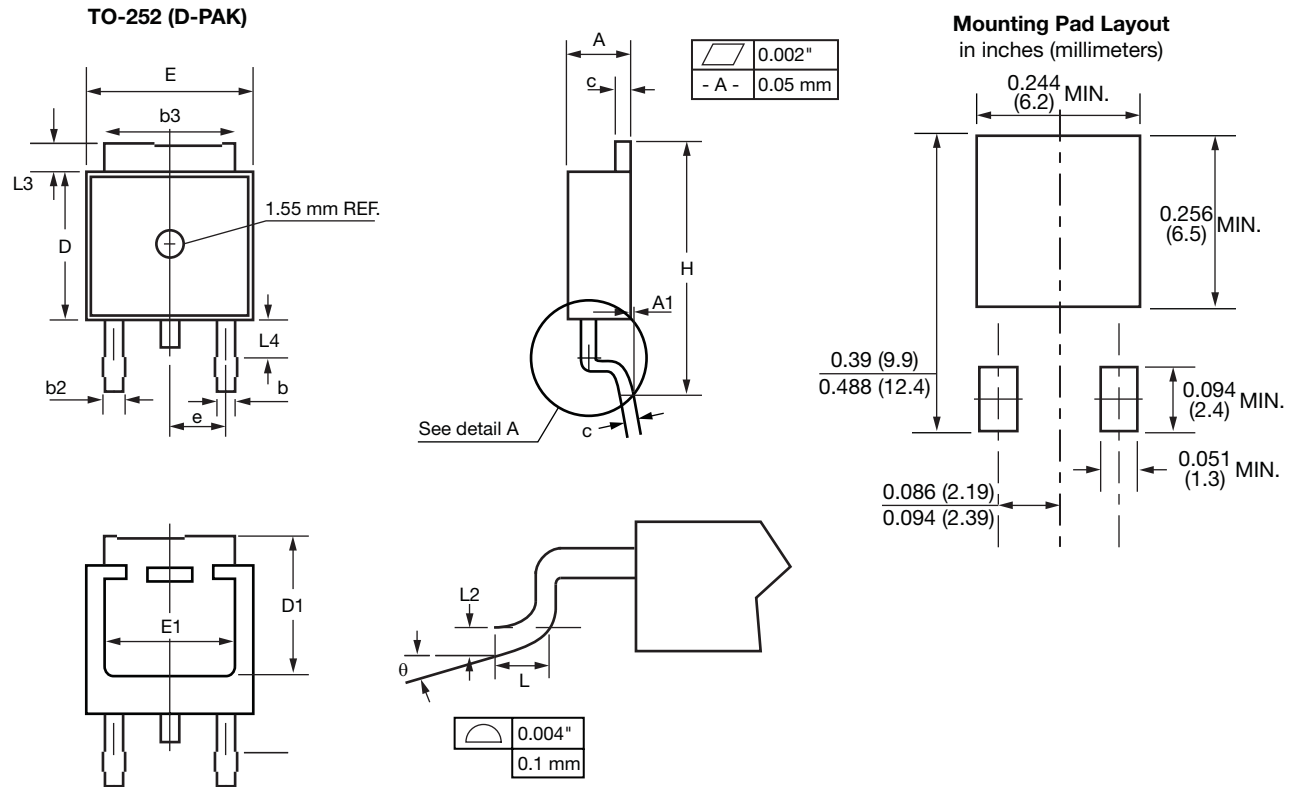


Fig. 6 - Typical Transient Thermal Impedance Per Device

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)


SYMBOL	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.086	0.094	2.19	2.38
A1	-	0.005	-	0.13
b	0.025	0.035	0.64	0.89
b2	0.033	0.045	0.84	1.14
b3	0.205	0.215	5.21	5.46
c	0.018	0.024	0.46	0.61
D	0.235	0.250	5.97	6.22
D1	0.205	-	5.21	-
E	0.250	0.265	6.35	6.73
E1	0.190	-	4.83	-
e	0.090 BSC.		2.29 BSC.	
H	0.380	0.410	9.65	10.41
L	0.055	0.070	1.40	1.78
L2	0.020 BSC.		0.51 BSC.	
L3	0.035	0.050	0.89	1.27
L4	0.025	0.039	0.64	1.01
$\theta$	0°	8°	0°	8°

**Note**

- Conforms to JEDEC TO-252 variation AA except dimension "D"



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